

R8A66160DD/SP 16-BIT LED DRIVER WITH SHIFT REGISTER AND LATCH

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DESCRIPTION

R8A66160 is a LED array driver having a 16-bit serial input and parallel output shift register function with direct coupled reset input and output latch function.

This product guarantees the output current of 24mA (Vcc =5V case) which is sufficient for cathode common LED drive, capable of following 16-bits continuously at the same time. Parallel output is open drain output. In addition, as this product has been designed in complete CMOS, power consumption can be greatly reduced when compared with conventional BIPOLAR or Bi-CMOS products. Furthermore, pin layout ensures the realization of an easy printed circuit. R8A66160 is the succession product of M66310.

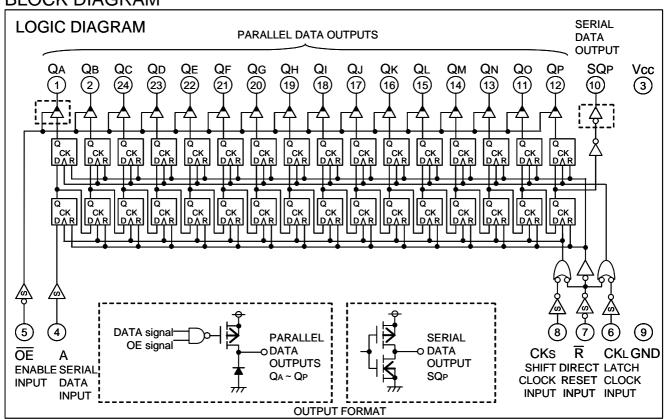
FEATURES

- Cathode common LED drive
- Vcc 5V or 3.3V single power supply
- High output current: all parallel outputs QA~QP IOH=-24mA (at VCC =5.0V) IOH=-12mA (at VCC =3.3V) simultaneous lighting available
- Low power dissipation: 100uW/package (max) (Vcc=5.0V, Ta=25°C, quiescent state)
- High noise margin: Schmitt input circuit provides responsiveness to a long line length
- Equipped with direct-coupled reset
- Open drain output: (except serial data output SQP)
- Wide operating temperature range: Ta=-40°C~+85°C
- Pin layout facilitates printed circuit wiring. (This layout facilitates cascade connection and LED connection)

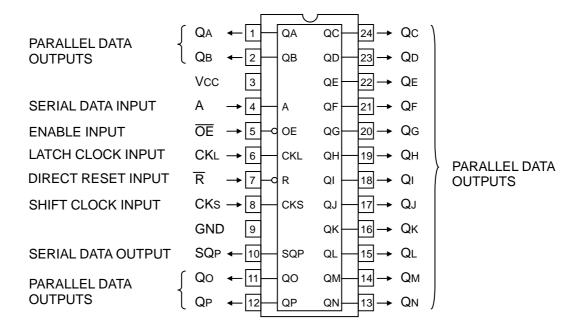
APPLICATION

- LED array drive. The various LED display modules
- PPC, Printer, VCR, Mini-compo, Button-Telephone etc. All of LED display equipment

BLOCK DIAGRAM



PIN CONFIGURATION (TOP VIEW)



FUNCTIONAL DESCRIPTION

As R8A66160 uses silicon gate CMOS process. It realizes high-speed and high-output currents sufficient for LED drive while maintaining low power consumption and allowance for high noises.

Each bit of a shift register consists of two flip-flop having independent clocks for shifting and latching.

As for clock input, shift clock input CKs and latch clock input CKL are independent from each other, shift and latch operations being made when "L" changes to "H".

Serial data input A is the data input of the first-step shift register and the signal of A shifts shifting registers one by one when a pulse is impressed to CKs. When A is "L", the signal of "L" shifts.

When the pulse is impressed to CKL, the contents of the shifting register at that time are stored in a latching register, and they appear in the parallel data outputs from QA ~ QP.

Outputs QA ~ QP are open drain outputs.

To extend the number of bits, use the serial data output SQP which shows the output of the shifting register of the 16th bit.

When reset input R is changed to "L", QA ~ QP and SQP are reset. In this case, shifting and latching register are reset.

If "H" is impressed to output enable input OE, QA ~ QP reaches the high impedance state, but SQP does not reach the high impedance state. Furthermore, change in OE does not affect shift operation.

FUNCTION TABLE (Note: 1)

			I	nput									Paral	lel da	ita ou	tput							Serial	Remarks
Operati	ion mode	R	CKs	CK∟	Α	ŌE	QΑ	Qв	Qc	Qυ	QE	QF	QG	Qн	Qi	QJ	Qĸ	QL	Qм	QN	Qo	QΡ	output SQP	Remarks
Re	eset	L	Х	Х	Х	Х	Ζ	Ζ	Z	Z	Z	Ζ	Ζ	Ζ	Ζ	Ζ	Ζ	Ζ	Z	Z	Ζ	Ζ	L	_
	Shift t ₁	Н		Х	Н	L	QÃ	QB	Q ပ္	ο _Ω	٥ Q	QF ⁰	QG	QH	Qن	တိ	Qĸ	Qڵ	ом Qм	QN QN	ထို	QP	qδ	Output lighting
Shift Latch	Latch t2	Н	Х		Х	L	Н	q _A 0	q _B 0	qc0	db ₀	qE0	qF0	dΘ	qнρ	qı o	$d\gamma_0$	qĸ ⁰	qL0	ф	dν ₀	ф	qσ	"H"
operation	Shift t1	Н		х	L	L	QÃ	QB	Qc	Qu	QE	QF	QG	Qμ	Qı ⁰	Qυ	Qĸ	Q۲٥	Qм	QN	Qo	Q₽	qo0	Output
	Latch t2	Н	Х		Х	L	Ζ	q _A 0	q _B 0	qc0	db₀	qE0	qF0	d€	qн	qı o	dηo	qk0	qL0	ф	dν ₀	ф	qo0	lights-out "L"
Output	disable	Х	Х	Х	Х	Н	Z	Z	Z	Z	Z	Ζ	Ζ	Ζ	Z	Z	Z	Ζ	Z	Z	Z	Z	qР	_

: Change from low-level to high-level Q⁰: Output state Q before CKL changed Note1:

X: Irrelevant

: Contents of shift register before CKs changed

: Contents of shift register : t2 is set after t1 is set : High Impedance

ABSOLUTE MAXIMUM RATINGS (Ta=-40~+85°C, unless otherwise noted)

Symbol	Parameter		Conditions	Ratings	Unit
VCC	Supply voltage			-0.5 ~ +7.0	V
VI	Input voltage			-0.5 ~ VCC+0.5	V
Vo	Output voltage			-0.5 ~ VCC+0.5	V
Ю	Output current per	QA ~ QP		-50	mA
Ю	output pin	SQP		±25	IIIA
ICC	Supply / GND current		VCC, GND	-410, +20	mA
Pd	Power dissipation		(Note 2)	500	mW
Tstg	Storage temperature range			-65 ~+150	°C

Note 2: R8A66160SP; Ta=-40~+70°C, Ta=+70~+85°C are derated at -6mW/°C.

RECOMMENDED OPERATING CONDITIONS (Ta=-40~+85°C, unless otherwise noted)

Symbol	Parameter		Unit			
Symbol	i alametei	Min.	Тур.	Max.	Offic	
VCC	Supply voltage	5.0V support		5.0	5.5	V
VCC	Supply voltage	3.0	3.3	3.6	V	
VI	Input voltage		0		VCC	V
Vo	Output voltage		0		VCC	V
Topr	Operating temperature range		-40		+85	°C

ELECTRICAL CHARACTERISTICS

■5.0V version support specifications (Ta=-40~+85°C,Vcc=4.5V~5.5V, unless otherwise noted)

Symbol	Paramete	r	Tost or	onditions		Unit			
Symbol	Faramete	ı	Test co	oriditions	Min.	Тур.	Max.	Offic	
VT+	Positive-going threshold voltage		VO=0.1V, VCC-0.1V IO =20uA		0.35xVCC		0.70xVCC	٧	
VT-	Negative-going thres voltage	hold	VO=0.1V, VCC IO =20uA	-0.1V	0.20xVCC		0.55xVCC	V	
Voн			VI=VT+,VT-	IOH= -20uA	VCC-0.1				
	High-level output voltage	QA ~ QP	VCC=4.5V	IOH= -24mA	3.66			V	
			(Note3)	IOH= -40mA	3.25				
VOH	High-level output	SQP	VI=VT+,VT-	IOH= -20uA	VCC-0.1			V	
VOH	voltage	SQP	VCC=4.5V	IOH= -4mA	3.66			v 	
VOL	Low-level output	SQP	VI=VT+,VT- IOL= 20uA				0.10	V	
VOL	voltage	SQP	VCC=4.5V	IOL= 4mA			0.53	V	
liH	High-level input curre	ent	VI=VCC, VCC=	5.5V			5	uA	
lıL	Low-level input curre	nt	VI=GND, VCC=	=5.5V			-5	uA	
IO	Maximum output	QA ~ QP	VI=VT+,VT-	VO=VCC			10	uA	
Ю	leakage current	QA~QP	VCC=5.5V	VO=GND			-10	uA	
ICC	Quiescent supply current		VI=VCC,GND, VCC=5.5V				200	uA	

Note 3: R8A66160 is used under the condition of an output current IOH=-40mA, the number of simultaneous drive outputs is restricted as shown in the Duty Cycle – IOH of TYPICAL CHARACTERISTICS.

■3.3V version support specifications (Ta=-40~+85°C,Vcc=3.0V~3.6V, unless otherwise noted)

Cumbal	Paramete	-	Toot or	onditions		Unit			
Symbol	T arameter		Test Co	oriditions	Min.	Тур.	Max.	Offic	
VT+	Positive-going threshold voltage		VO=0.1V, VCC-0.1V IO =20uA		0.35xVCC		0.70xVCC	V	
VT-	Negative-going thres voltage	hold	VO=0.1V, VCC IO =20uA	C-0.1V	0.20xVCC		0.55xVCC	V	
				IOH= -20uA	VCC-0.1				
	High-level output voltage	QA ~ QP	VI=VT+,VT- VCC=3.0V	IOH= -12mA	2.34			٧	
			100-0.01	IOH= -20mA	2.08				
Vон	High-level output	SQP	VI=VT+,VT-	IOH= -20uA	VCC-0.1			V	
VOH	voltage	SQP	VCC=3.0V	IOH= -2mA	2.60			v	
VOL	Low-level output	SQP	VI=VT+,VT-	IOL= 20uA			0.10	V	
VOL	voltage	SQP	VCC=3.0V	IOL= 2mA			0.40		
liH	High-level input curre	ent	VI=VCC, VCC=	=3.6V			5	uA	
IIL	Low-level input curre	nt	VI=GND, VCC=3.6V				-5	uA	
10	Maximum output	QA ~ QP	VI=VT+,VT-	VO=VCC			10	uA	
Ю	leakage current	QA~QP	VCC=3.6V	VO=GND			-10	uA	
ICC	Quiescent supply current		VI=VCC,GND, VCC=3.6V				200	uA	

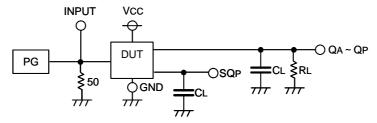
SWITCHING CHARACTERISTICS (Ta=-40~+85°C,Vcc=5.0V or 3.3V)

Symbol	Parameter		Test	5.0V	specific	ation	3.3V	Unit		
Symbol	Faramen	5 1	conditions	Min.	Тур.	Max.	Min.	Тур.	Max.	Offic
fmax	Maximum clock frequency					4			3.3	MHz
tPLH	Output "L"-"H" and "H"-"L"	CKs - SQP				125			150	ns
tPHL	propagation time	CNS - SQP				125			150	ns
tPHL	Output "H"-"L" propagation time	R - SQP				125			150	ns
tPHZ	Output "H"-"Z" propagation time	R - QA ~ QP (turned off)	CL=50pF			200			220	ns
tPZH	Output "Z"-"H" propagation time	CKL - QA ~ QP (turned on)	RL=1KΩ (Note 4)			125			150	ns
tPHZ	Output "H"-"Z" propagation time	CKL - QA ~ QP (turned off)				200			220	ns
tPZH	Output "Z"-"H" propagation time	OE - QA ~ QP (turned on)				125			150	ns
tPHZ	Output "H"-"Z" propagation time	OE - QA ~ QP (turned off)				200			220	ns
CI	Input capacitance					10			10	pF

TIMING REQUIREMENTS (Ta=-40~+85°C,Vcc=5.0V or 3.3V)

Symbol	Parameter	Test	5.0V	specific	ation	3.3V	Unit		
Symbol	Farameter	conditions	Min.	Тур.	Max.	Min.	Тур.	Max.	OTIL
tw	CKS, CKL, R pulse width		125			150			ns
tsu	A setup time with respect to CKS		125			150			ns
tsu	CKS setup time with respect to CKL	(Note 4)	125			150			ns
th	A hold time with respect to CKS		15			20			ns
trec	R recovery time with respect to CKS, CKL		70			80			ns

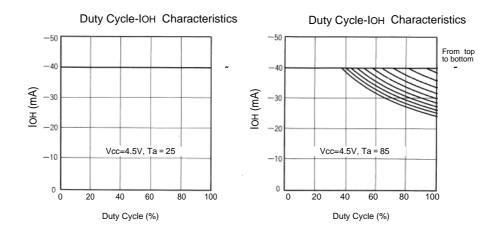
Note4: Test Circuit



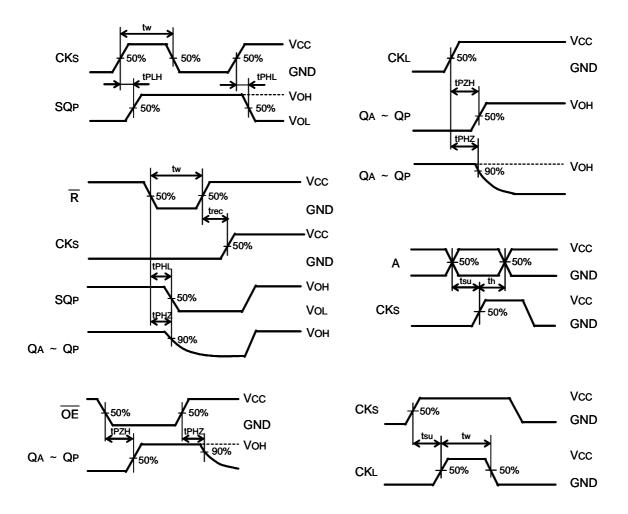
- (1) The pulse generator (PG) has the following characteristics (10%~90%): tr=6ns,tf=6ns
- (2) The capacitance CL includes stray wiring capacitance and the probe input capacitance.

TYPICAL CHARACTERISTICS

- Repetition frequency > 10Hz
- Numbers in indicate the number of output circuits that operate simultaneously.
- · Current values are per circuit.

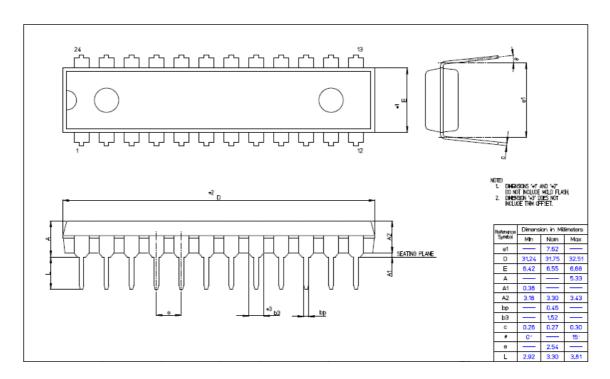


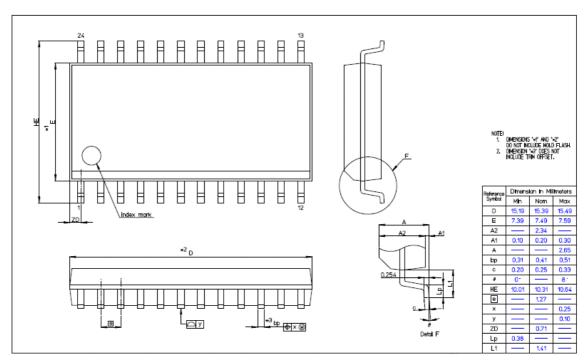
TIMING DIAGRAM



PACKAGE OUTLINE

Product name	Package	RENESAS Code	Previous Code
R8A66160DD	24pin DIP	PRDP0024AF-A	24P4X-A
R8A66160SP	24pin SOP	PRSP0024DF-A	24P2X-B





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